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Numerical simulations and experimental observation of photonic nanojets generated by TiO₂ microparticles

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Motivation

How could one get a high sensitivity of the optical sensor for chemical compounds?

1. Use of ultra-high light localization in a near-field of an optical resonator*



Advances: high light localization intensities provide a single-molecule detection. Drawbacks: the probability of analyte molecule to reach a localization area is too small.

Solution: to use a photonic nanojet phenomena for extended light localization in a sensitive layer of the optical sensor.

*F. Vollmer, L. Yang, Nanophotonics 1 (2012) 267–291

Motivation

How could one get a high sensitivity of the optical sensor for chemical compounds?



2. Extended light localization using photonic nanojets

Advances: Extended light localization area increases probability of analyte detection. Tracking of analyte concentration. Possibility of sensing arrays formation.

<u>Challenges</u>: Development of fabrication technique of a parental microstructure array. Optimization of microstructure parameters to achieve the highest performance.

Experimental setup



Sample preparation



Sensitive layer: chitosan polymer doped by rhodamine 6G derivate*

*A.Yu. Mironenko et al. Tetrahedron 75 (2019) 1492–1496

Analyte: Au³⁺ ions

Numerical simulations

The developed structures can generate PNJ both in reflection and transmission modes



Once the microstructure is placed at a certain distance from the substrate it is possible to obtain **PNJ in reflection mode without standing wave modulation**!

Sensor response



Sensor response



Concept Incident light Sensitive layer •eff PNJ Gap **PMMA** M Si

- (a) Scheme of fabrication process(b) AFM-images of templates
- (b) AFM-images of templates(c) SEM image of fabricated ar
- (c) SEM-image of fabricated array
- (d) Optical-image of fabricated array



y, μm

Numerical simulations



PNJ with the **highest intensity** appears at **certain** gap between the hemisphere and the substrate!

Experimental images



(a, e) 1 μ m hemisphere, gap 0.2 μ m (b, f) 1 μ m hemisphere, gap 0 μ m (c, g) 2µm hemisphere, gap 0.05 µm (d, h) $2\mu m$ hemisphere, gap $0 \mu m$ 8

Photoluminescence enhancement



(a) 1 μ m hemisphere, gap 0 μ m; (b) 1 μ m hemisphere, gap 0.2 μ m; (c) 2 μ m hemisphere, gap 0 μ m; (d) 2 μ m hemisphere, gap 0.05 μ m

Photoluminescence enhancement



According to previous results, the 7-fold enhanced photoluminescence (2µm hemisphere, gap 0.05 µm) leads to a reasonable enhancement of the sensor response.



(a) 1 μ m hemisphere, gap 0 μ m; (b) 1 μ m hemisphere, gap 0.2 μ m; (c) 2 μ m hemisphere, gap 0 μ m; (d) 2 μ m hemisphere, gap 0.05 μ m

Conclusion

- 1. Different types of PNJ generating microstructures were studied in the terms of photoluminescence and sensor performance enhancement.
- 2. The technique for fabrication of the ordered close-packed arrays of parental microstructures had been developed.
- 3. The limit of detection of the sensitive layer excited by PNJ depends on its length, while the photoluminescence and sensor response depend on the PNJ intensity.
- 4. The new type of PNJ in reflection mode without modulation by the standing wave was observed.

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